Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

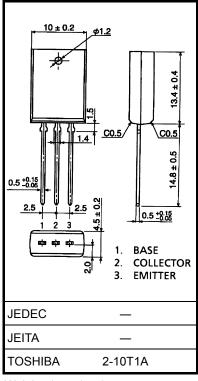
## 2SC5684

# Switching Regulator and High-Voltage Switching Applications

- Excellent switching times (I<sub>C</sub> = 0.3 A)
   : t<sub>r</sub> = 0.7 μs (max), t<sub>f</sub> = 0.5 μs (max)
- High collector breakdown voltage:  $V_{CEO} = 800 \text{ V}$
- High-speed DC-DC converter applications

#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	900	V	
Collector-emitter voltage		V <sub>CEO</sub>	800	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ic	0.8	Α	
	Pulse	I <sub>CP</sub>	1.5		
Base current		Ι <sub>Β</sub>	0.4	Α	
Collector power dissipation		PC	1.8	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 1.5 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

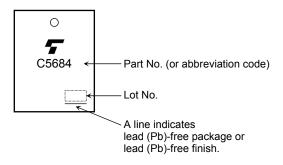
temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## **Electrical Characteristics (Ta = 25°C)**

Chara	Characteristics Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 720 V, I <sub>E</sub> = 0	_	_	100	μΑ
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	1	mA
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	900	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	800	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	10	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.08 A	15	_	60	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.06 A	_	_	1.0	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.06 A	_	_	1.2	V
Switching time Storage	Rise time	t <sub>r</sub>	20 µs Input → CC B2 NCC ≈ 360 V	_	_	0.7	
	Storage time	t <sub>stg</sub>		_	_	4.5	μs
	Fall time	t <sub>f</sub>	$I_{B1} = 0.06 \text{ A}, I_{B2} = -0.12 \text{ A}$ Duty cycle $\leq 1\%$	_	_	0.5	

## Marking



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20070701-EN

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